## REMARKS

Claims 3, 4 and 7 have been amended to avoid the multiple dependent claim surcharge. Claims 21-26 presented herein correspond to the dependencies eliminated from the amended claims.

The Commissioner is hereby authorized to charge to

Deposit Account No. 50-1165 any fees that may be required by

this paper and to credit any overpayment to that Account.

Respectfully submitted,

MWS: jab

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December 5, 2001

Mitchell W. Shapiro Reg. No. 31,568

## MARKED-UP VERSION OF THE CLAIMS:

- 3. (Amended) A semiconductor device according to Claim 1
- 2 [or Claim 2], wherein a power supply voltage applied to the
- 3 first MOS transistors constituting the input circuit or the
- 4 output circuit is equal to a power supply voltage applied to
- 5 the second MOS transistors constituting the internal circuit.
- 4. (Amended) A semiconductor device according to Claim 2
  [32] [or Claim 3], wherein a gate length of the first MOS
  [33] transistors is equal to a gate length of the second MOS
  [34] transistors.
- - 4 output circuit is higher than a power supply voltage applied
  - 5 to the second MOS transistors constituting the internal
  - 6 circuit.

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